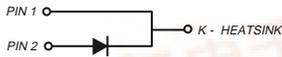
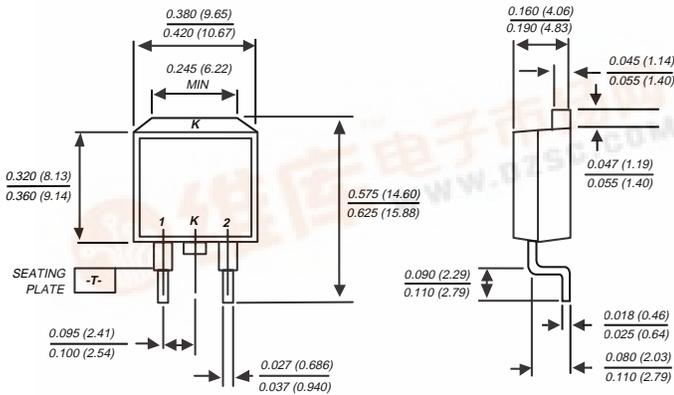


# FESB8AT THRU FESB8JT

## FAST EFFICIENT PLASTIC RECTIFIER

Reverse Voltage - 50 to 600 Volts Forward Current - 8.0 Amperes

### TO-263AB



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Glass passivated chip junction
- ◆ Low leakage, high voltage
- ◆ High surge current capability
- ◆ Superfast recovery time, for high efficiency
- ◆ High temperature soldering in accordance with CECC 802 / Reflow guaranteed



### MECHANICAL DATA

**Case:** JEDEC TO-263AB molded plastic body  
**Terminals:** Plated lead solderable per MIL-STD-750, Method 2026  
**Polarity:** As marked  
**Mounting Position:** Any  
**Weight:** 0.08 ounce, 2.24 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	FESB 8AT	FESB 8BT	FESB 8CT	FESB 8DT	FESB 8FT	FESB 8GT	FESB 8HT	FESB 8JT	UNITS
Maximum recurrent peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	500	600	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	350	420	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	500	600	Volts
Maximum average forward rectified current at T <sub>C</sub> =100°C	I <sub>(AV)</sub>	8.0								Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	125.0								Amps
Maximum instantaneous forward voltage at 8.0A	V <sub>F</sub>	0.95		1.3		1.5				Volts
Maximum DC reverse current at rated DC blocking voltage at T <sub>C</sub> =100°C	I <sub>R</sub>	10.0 500.0								μA
Maximum reverse recovery time (NOTE 1)	t <sub>rr</sub>	35.0				50.0				ns
Typical junction capacitance (NOTE 2)	C <sub>J</sub>	85.0						50.0		pF
Typical thermal resistance (NOTE 3)	R <sub>θJC</sub>	3.0								°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150								°C

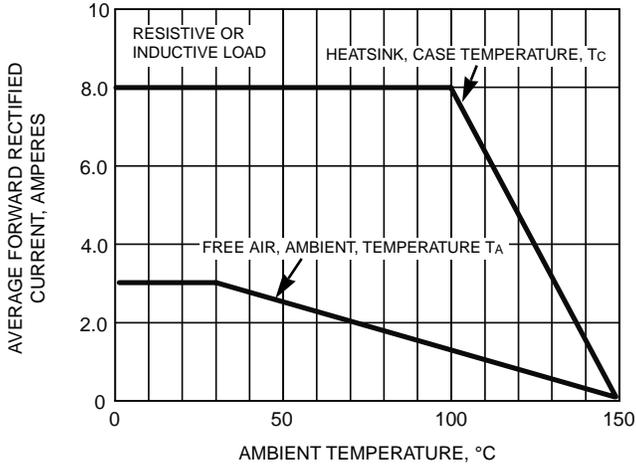
#### NOTES:

- (1) Reverse recovery test conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>rr</sub>=0.25A
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (3) Thermal resistance from junction to case mounted on heatsink

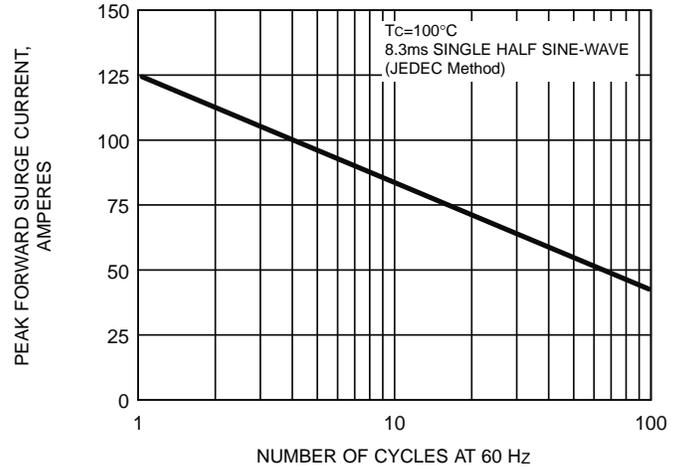


# RATINGS AND CHARACTERISTIC CURVES FESB8AT THRU FESB8JT

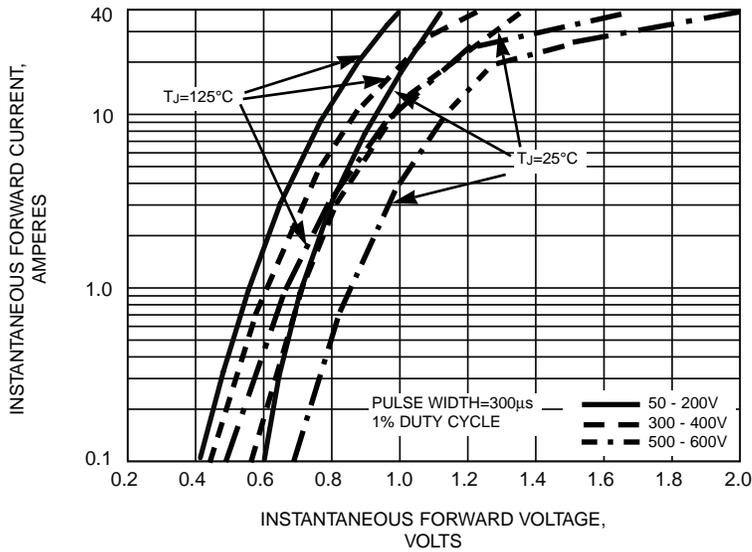
**FIG. 1 - MAXIMUM FORWARD CURRENT DERATING CURVES**



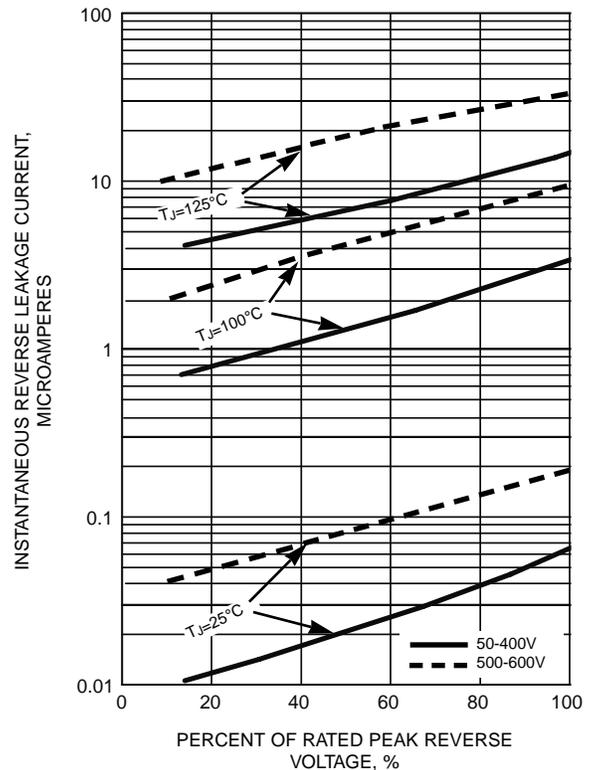
**FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS**



**FIG. 4 - TYPICAL REVERSE LEAKAGE CHARACTERISTICS**



**FIG. 5 - TYPICAL JUNCTION CAPACITANCE**

